

## Product / Process Change Notice

**Parts Affected:**

Chip process CP389, N-channel MOSFETs, wafers and bare die

**Extent of Change:**

The CP389 wafer process is being replaced by the CP400 wafer process. See figures 1 and 2 for details.

**Reason for Change:**

The CP389 wafer process is being replaced by the CP400 wafer process to enhance the manufacturing process controls and performance. This change will help ensure an undisrupted supply of product. The wafer size has increased from 6 inch to 8 inches in order to improve throughput.

**Effect of Change:**

The CP400 wafer process meets all electrical specifications of the individual devices listed on the following page.

**Qualification:**

P/N: CP400 Chip Process

Package: TO-220FP

No.	Test	Conditions (Reference standards are in bold)	Qty	Pass/Fail	Test Results
<b>1</b>	<b>Device Life Tests</b>				
a	High Temperature Gate Reverse Bias (HTGB)	T=150°C, t = 1000 hours 100% VGS=30V <b>JESD22-A110</b>	45	Pass	45/45
b	High Temperature Reverse Bias (HTRB)	T=150°C, t = 1000 hours VDS=600V <b>JESD22-A108</b>	45	Pass	45/45
C	High Accelerated Temperature and Humidity Stress Test (HAST)	T=130°C, t = 96 hours, 85%RH, 230kPa, VDS=42V <b>JESD22-A108</b>	45	Pass	45/45
D	Temperature Cycling (TC)	-65°C -+150°C, Tdwell ≥10min, 500 cycles	45	Pass	45/45

**PCN #182**  
**Notification Date:**  
**27 April 2020**

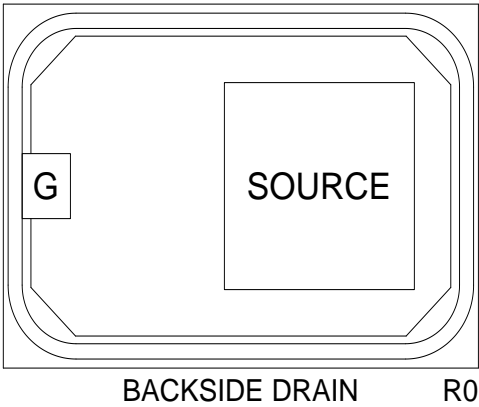
**Effective Date of Change:**

Existing inventory of chip process CP389 will be shipped until depleted.

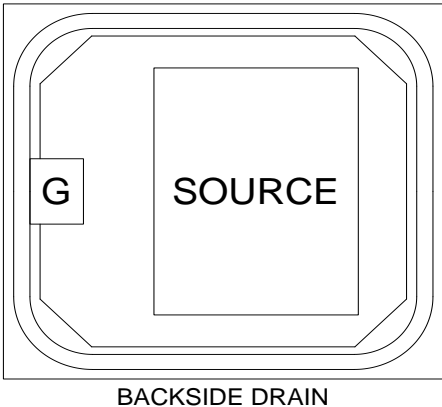
**Sample Availability:**

Please contact your salesperson or manufacturer's representative for samples.

**Figure 1: CP389 Chip Geometry**



**Figure 2: CP400 Chip Geometry**



Wafer Diameter: 6 inch  
Die Size: 137.8 x 96.9 mils  
Die Thickness: 9.1 mils  
Bond Pad Size (Gate): 13.98 x 17.32 mils  
Bond Pad Size (Source): 55.1 x 55.1 mils  
Topside Metal: Al (43,000Å)  
Backside Metal: Ag (8,000Å)

Wafer Diameter: 8 inch  
Die Size: 110.2 x 101.6 mils  
Die Thickness: 9.1 mils  
Bond Pad Size (Gate): 13.4 x 17.7 mils  
Bond Pad Size (Source): 51.2 x 66.9 mils  
Topside Metal: Al (43,000Å)  
Backside Metal: Ag (8,000Å)

**Part Numbers Affected:**

CDM7-600LR	CP389-CDM7-600LR-CT
	CP389-CDM7-600LR-WN



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<https://www.centrialsemi.com/process-change-notice>

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As per JEDEC standard JESD46, Customer Notification of Product/Process Changes by Solid-State Suppliers, a lack of acknowledgement of a PCN within thirty (30) days constitutes acceptance of the change.

The undersigned acknowledges and accepts Central Semiconductor's Product/Process Change Notification (PCN).

Company Name:	
Address:	
Printed Name:	
Title:	
Signature:	
Date:	